

# Precision 600MHz to 7GHz, RF Detector with Adjustable Gain and 12MHz Baseband Bandwidth

## FEATURES

- Temperature Compensated Internal Schottky Diode RF Detector
- Wide Input Frequency Range: 600MHz to 7GHz\*
- Wide Input Power Range: -32dBm to 10dBm
- External Gain Control
- Precision  $V_{OUT}$  Offset Control
- Low Starting Voltage: 200mV for Gain = 2
- Wide  $V_{CC}$  Range of 2.7V to 5.5V
- Low Operating Current: 2mA
- Available in a Low Profile (1mm) SOT-23 Package

## APPLICATIONS

- 802.11a, 802.11b, 802.11g, 802.15, 802.16
- Multimode Mobile Phone Products
- Optical Data Links
- Wireless Data Modems
- Wireless and Cable Infrastructure
- RF Power Alarm
- Envelope Detector

## DESCRIPTION

The LTC<sup>®</sup>5535 is an RF power detector for RF applications operating in the 600MHz to 7GHz range. A temperature compensated Schottky diode peak detector and output amplifier are combined in a small ThinSOT<sup>™</sup> package. The supply voltage range is optimized for operation from a single cell lithium-ion or three cell NiMH battery.

The RF input voltage is peak detected using an on-chip Schottky diode. The detected voltage is buffered and supplied to the  $V_{OUT}$  pin.

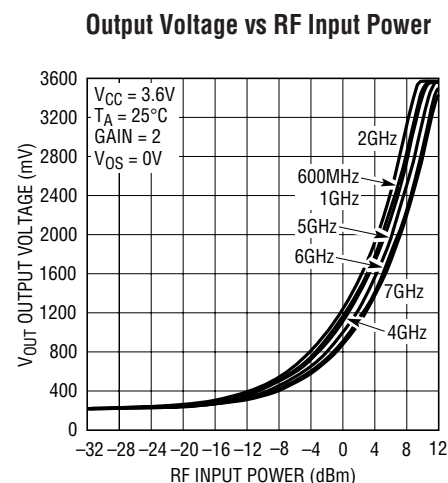
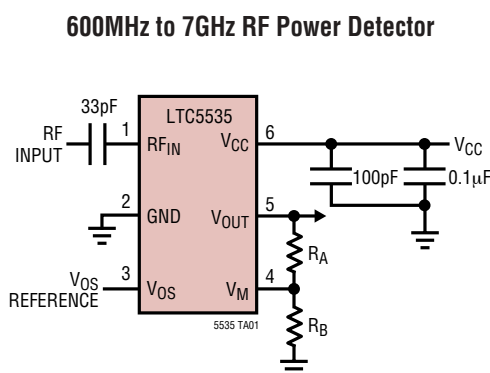
The LTC5535 output amplifier gain is set via external resistors. The initial starting voltage of 200mV can be precisely adjusted using the  $V_{OS}$  pin.

The LTC5535 operates with input power levels from -32dBm to 10dBm. The 12MHz baseband bandwidth is much higher than that of previous Schottky detector products.

**LT**, LTC and LT are registered trademarks of Linear Technology Corporation.  
ThinSOT is a trademark of Linear Technology Corporation.

\*Higher frequency operation is achievable with reduced performance. Consult factory for more information.

## TYPICAL APPLICATION



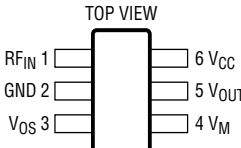
5535 TA02

## ABSOLUTE MAXIMUM RATINGS

(Note 1)

|                                               |                               |
|-----------------------------------------------|-------------------------------|
| $V_{CC}$ , $V_{OUT}$ , $V_M$ , $V_{OS}$ ..... | –0.3V to 6V                   |
| $RF_{IN}$ Voltage .....                       | ( $V_{CC} \pm 1.5V$ ) to 6.5V |
| $RF_{IN}$ Power (RMS) .....                   | 12dBm                         |
| $I_{VOUT}$ .....                              | 25mA                          |
| Operating Temperature Range (Note 2) ..       | –40°C to 85°C                 |
| Maximum Junction Temperature .....            | 125°C                         |
| Storage Temperature Range .....               | –65°C to 150°C                |
| Lead Temperature (Soldering, 10 sec) .....    | 300°C                         |

## PACKAGE/ORDER INFORMATION

|                                                                                                                                                                                                                                                                                                                   |                   |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|
|  <p>TOP VIEW</p> <p>RF<sub>IN</sub> 1 6 V<sub>CC</sub><br/>GND 2 5 V<sub>OUT</sub><br/>V<sub>OS</sub> 3 4 V<sub>M</sub></p> <p>S6 PACKAGE<br/>6-LEAD PLASTIC TSOT-23<br/>T<sub>JMAX</sub> = 125°C, θ<sub>JA</sub> = 250°C/W</p> | ORDER PART NUMBER |
|                                                                                                                                                                                                                                                                                                                   | LTC5535ES6        |
|                                                                                                                                                                                                                                                                                                                   | S6 PART MARKING   |
|                                                                                                                                                                                                                                                                                                                   | LBHK              |

Consult LTC Marketing for parts specified with wider operating temperature ranges.

## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ .  $V_{CC} = 3.6V$ , RF Input Signal is Off,  $R_A = R_B = 500\Omega$ ,  $V_{OS} = 0V$  unless otherwise noted.

| PARAMETER                         | CONDITIONS                                                                                             | MIN  | TYP         | MAX            | UNITS             |
|-----------------------------------|--------------------------------------------------------------------------------------------------------|------|-------------|----------------|-------------------|
| $V_{CC}$ Operating Voltage        | ●                                                                                                      | 2.7  |             | 5.5            | V                 |
| $I_{VCC}$ Operating Current       | $I_{VOUT} = 0\text{mA}$ ●                                                                              |      | 2           | 3.5            | mA                |
| $V_{OUT}$ $V_{OL}$ (No RF Input)  | ●                                                                                                      | 150  | 180 to 220  | 250            | mV                |
| $V_{OUT}$ Output Current          | $V_{OUT} = 1.75V$ , $V_{CC} = 2.7V$ to $5.5V$ , $\Delta V_{OUT} < 10\text{mV}$                         | 10   | 20          |                | mA                |
| $V_{OUT}$ Bandwidth               | $C_{LOAD} = 33\text{pF}$ , $R_{LOAD} = 2k$ , $P_{IN} = -10\text{dBm}$ (Note 4)                         |      | 12          |                | MHz               |
| $V_{OUT}$ Load Capacitance        | (Note 6) ●                                                                                             |      |             | 33             | pF                |
| $V_{OUT}$ Slew Rate               | $V_{RFIN} = 1V$ Step, $C_{LOAD} = 33\text{pF}$ (Note 3)                                                |      | 50          |                | V/ $\mu\text{s}$  |
| $V_{OUT}$ Noise                   | $V_{CC} = 3V$ , Noise BW = 1.5MHz, 50 $\Omega$ RF Input Termination, 50 $\Omega$ AC Output Termination |      | 1           |                | mV <sub>p-p</sub> |
| $V_{OS}$ Voltage Range            | ●                                                                                                      | 0    |             | 1              | V                 |
| $V_{OS}$ Input Current            | $V_{OS} = 1V$ ●                                                                                        | –0.5 |             | 0.5            | $\mu\text{A}$     |
| $V_M$ Voltage Range               | ●                                                                                                      | 0    |             | $V_{CC} - 1.8$ | V                 |
| $V_M$ Input Current               | $V_M = 3.6V$ ●                                                                                         | –0.5 |             | 0.5            | $\mu\text{A}$     |
| $RF_{IN}$ Input Frequency Range   |                                                                                                        |      | 600 to 7000 |                | MHz               |
| $RF_{IN}$ Input Power Range       | RF Frequency = 300MHz to 7GHz (Note 5, 6) $V_{CC} = 2.7V$ to 6V                                        |      | –32 to 10   |                | dBm               |
| $RF_{IN}$ AC Input Resistance     | $F = 1000\text{MHz}$ , $P_{in} = -25\text{dBm}$                                                        |      | 220         |                | $\Omega$          |
| $RF_{IN}$ Input Shunt Capacitance | $F = 1000\text{MHz}$ , $P_{in} = -25\text{dBm}$                                                        |      | 0.65        |                | pF                |

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** Specifications over the –40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

**Note 3:** The rise time at  $V_{OUT}$  is measured between 1.3V and 2.3V.

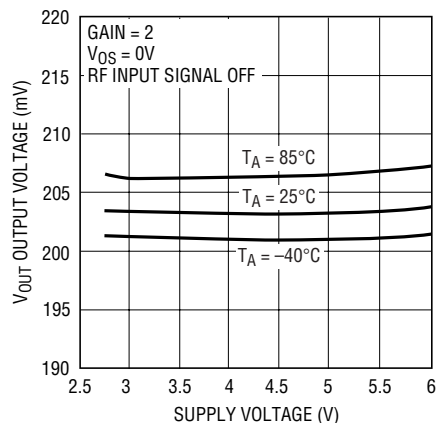
**Note 4:** See Table 1 in Applications Information section.

**Note 5:** RF performance is tested at 1800MHz

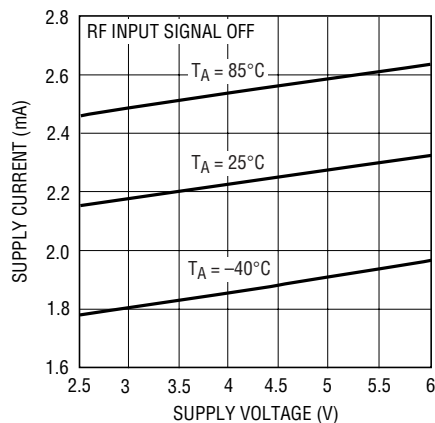
**Note 6:** Guaranteed by design.

# TYPICAL PERFORMANCE CHARACTERISTICS ( $R_{LOAD} = 1k = R_A + R_B$ )

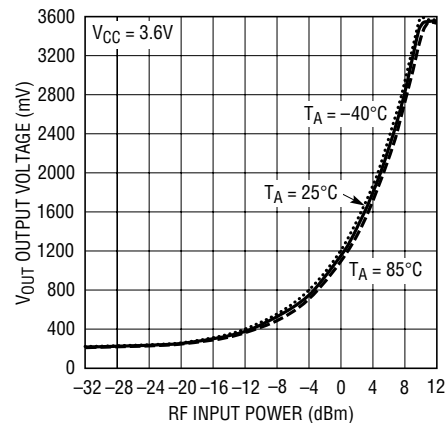
## Output Voltage vs Supply Voltage



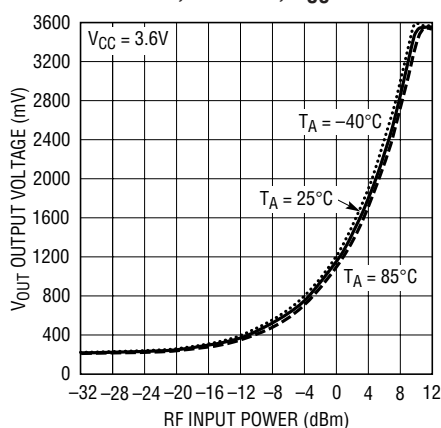
## Supply Current vs Supply Voltage



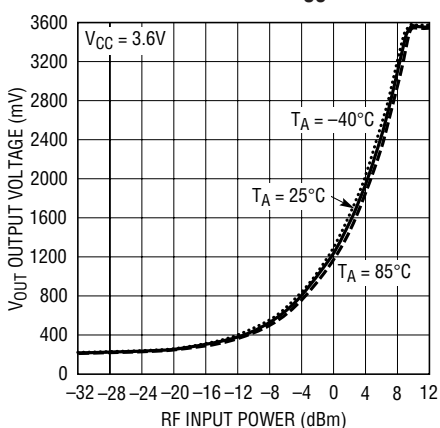
## Typical Detector Characteristics, 600MHz, Gain = 2, $V_{OS} = 0V$



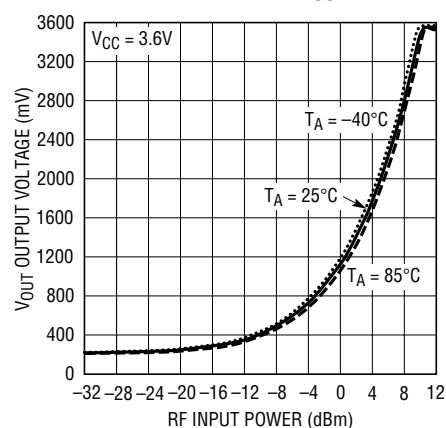
## Typical Detector Characteristics, 1000MHz, Gain = 2, $V_{OS} = 0V$



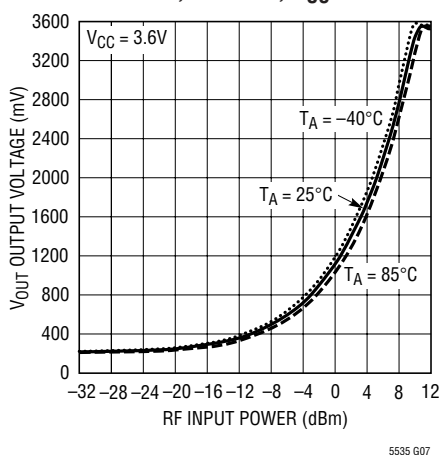
## Typical Detector Characteristics, 2000MHz, Gain = 2, $V_{OS} = 0V$



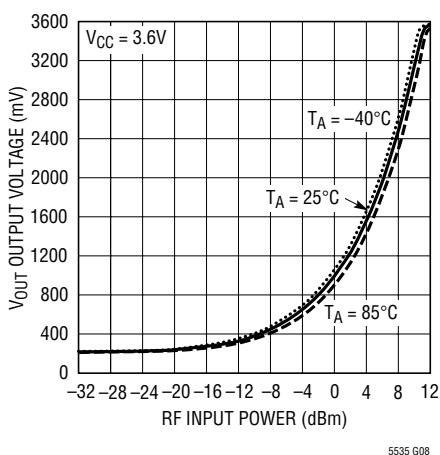
## Typical Detector Characteristics, 3000MHz, Gain = 2, $V_{OS} = 0V$



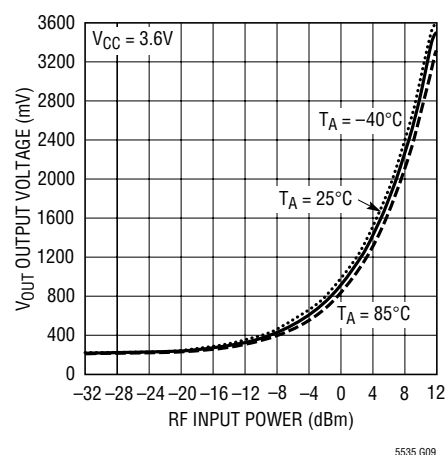
## Typical Detector Characteristics, 4000MHz, Gain = 2, $V_{OS} = 0V$



## Typical Detector Characteristics, 5000MHz, Gain = 2, $V_{OS} = 0V$

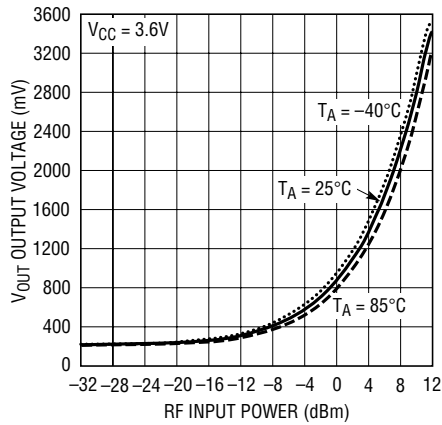


## Typical Detector Characteristics, 6000MHz, Gain = 2, $V_{OS} = 0V$

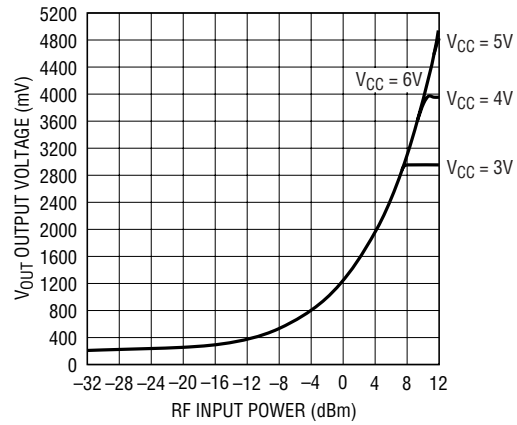


# TYPICAL PERFORMANCE CHARACTERISTICS ( $R_{LOAD} = 1k = R_A + R_B$ )

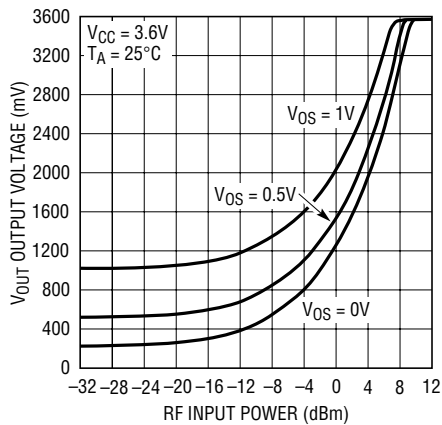
**Typical Detector Characteristics,  
7000MHz, Gain = 2,  $V_{OS} = 0V$**



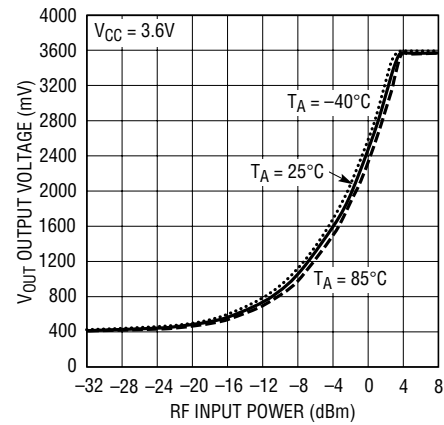
**$V_{OUT}$  vs RF Input Power and  $V_{CC}$ ,  
2000MHz, Gain = 2,  $V_{OS} = 0V$ ,  
 $T_A = 25^\circ C$**



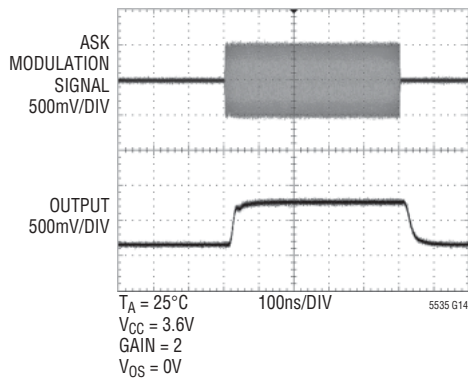
**$V_{OUT}$  vs RF Input Power and  $V_{OS}$ ,  
2000MHz, Gain = 2**



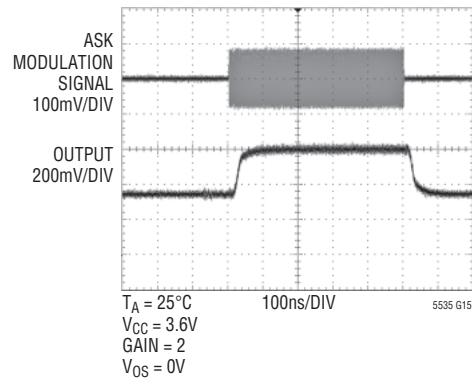
**Typical Detector Characteristics,  
2000MHz, Gain = 4,  $V_{OS} = 0V$**



**Time Domain Response at  
 $f_{RF} = 1900MHz$ ,  $P_{RF} = 0dBm$**

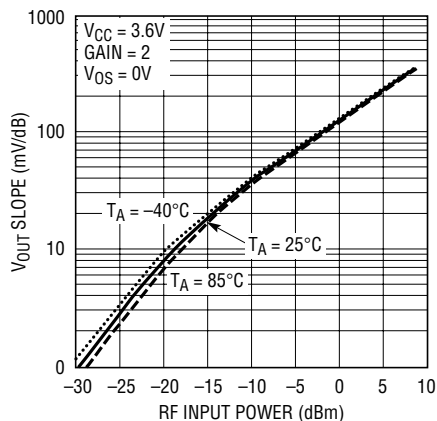


**Time Domain Response at  
 $f_{RF} = 1900MHz$ ,  $P_{RF} = -10dBm$**



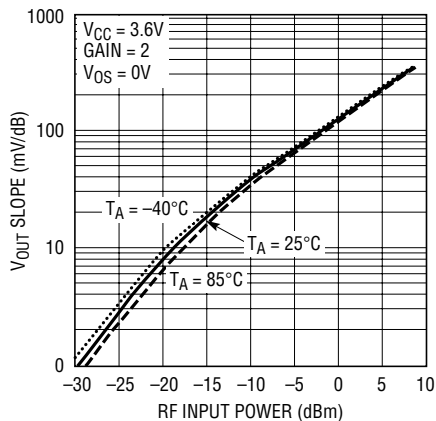
# TYPICAL PERFORMANCE CHARACTERISTICS ( $R_{LOAD} = 1k = R_A + R_B$ )

**$V_{OUT}$  Slope vs RF Input Power  
at 600MHz**



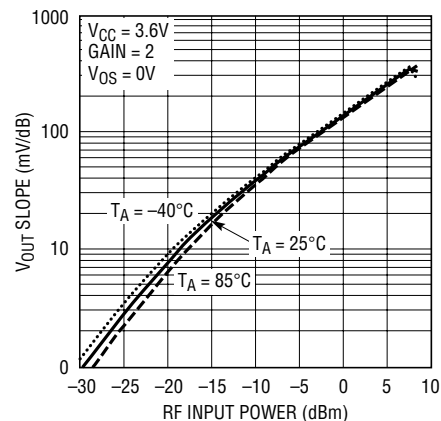
5535 G16

**$V_{OUT}$  Slope vs RF Input Power  
at 1000MHz**



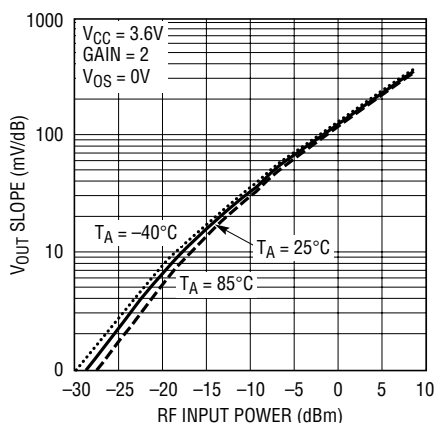
5535 G17

**$V_{OUT}$  Slope vs RF Input Power  
at 2000MHz**



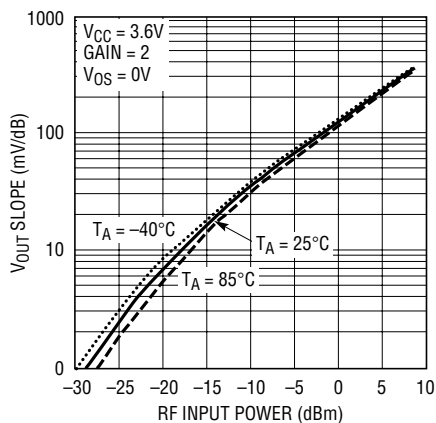
5535 G18

**$V_{OUT}$  Slope vs RF Input Power  
at 3000MHz**



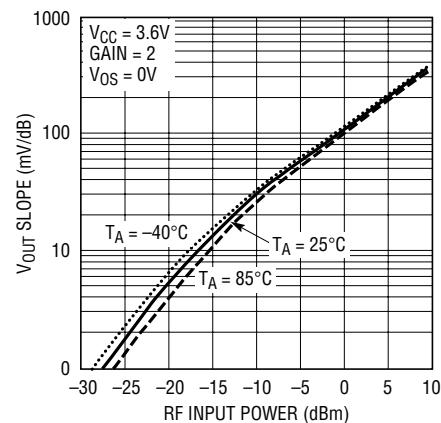
5535 G19

**$V_{OUT}$  Slope vs RF Input Power  
at 4000MHz**



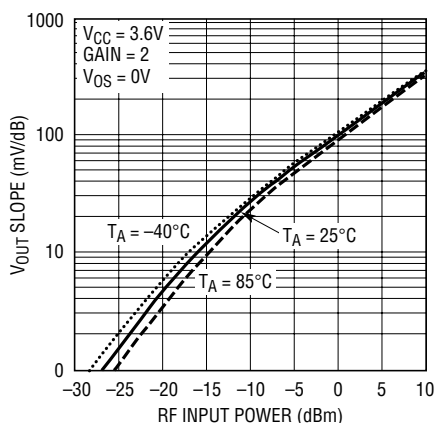
5535 G20

**$V_{OUT}$  Slope vs RF Input Power  
at 5000MHz**



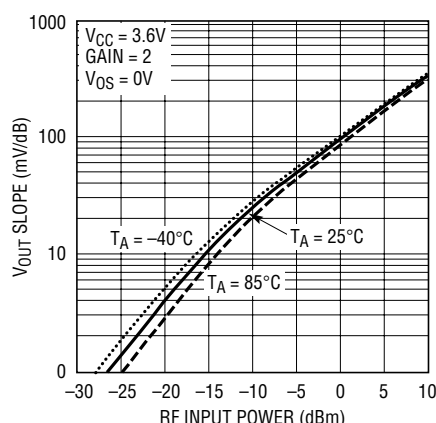
5535 G21

**$V_{OUT}$  Slope vs RF Input Power  
at 6000MHz**



5535 G22

**$V_{OUT}$  Slope vs RF Input Power  
at 7000MHz**



5535 G23

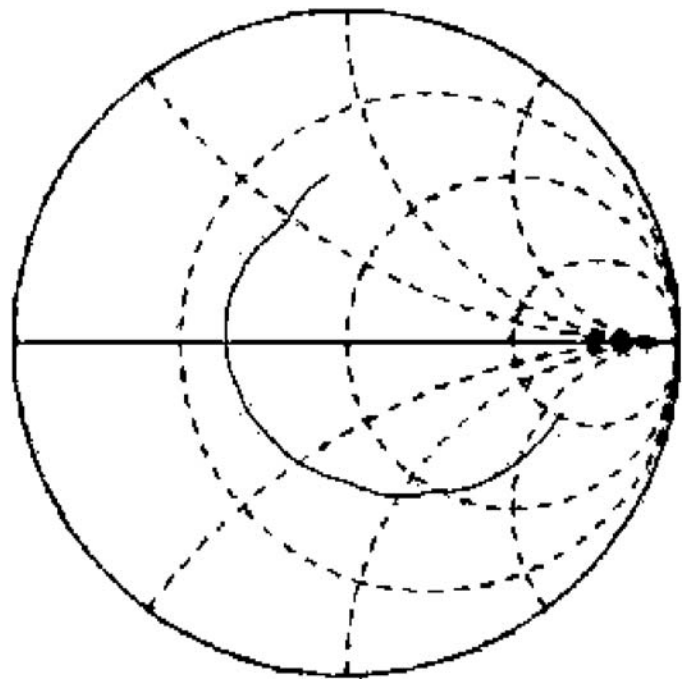
## TYPICAL PERFORMANCE CHARACTERISTICS

RF<sub>IN</sub> Input Impedance (Pin = -25 dBm, V<sub>CC</sub> = 3.6V, T<sub>A</sub> = 25°C)

| FREQUENCY<br>GHz | RESISTANCE<br>(Ω) | REACTANCE<br>(Ω) |
|------------------|-------------------|------------------|
| 0.600            | 156.68            | -127.09          |
| 0.728            | 135.50            | -122.64          |
| 0.856            | 118.45            | -116.93          |
| 0.984            | 104.52            | -110.97          |
| 1.112            | 92.64             | -105.02          |
| 1.240            | 83.35             | -98.29           |
| 1.368            | 75.36             | -92.40           |
| 1.496            | 68.73             | -86.52           |
| 1.624            | 63.20             | -80.86           |
| 1.752            | 58.56             | -75.65           |
| 1.880            | 54.68             | -70.56           |
| 2.008            | 51.40             | -65.59           |
| 2.136            | 49.37             | -60.89           |
| 2.264            | 47.90             | -57.97           |
| 2.392            | 44.55             | -55.20           |
| 2.520            | 41.81             | -51.32           |
| 2.648            | 39.91             | -47.76           |
| 2.776            | 38.28             | -44.50           |
| 2.904            | 37.15             | -41.35           |
| 3.032            | 35.94             | -38.47           |
| 3.160            | 34.94             | -35.89           |
| 3.288            | 33.78             | -33.39           |
| 3.416            | 32.33             | -30.93           |
| 3.544            | 31.04             | -28.47           |
| 3.672            | 29.80             | -25.80           |
| 3.800            | 28.71             | -23.12           |
| 3.928            | 27.85             | -20.43           |
| 4.056            | 27.29             | -18.04           |
| 4.184            | 26.34             | -15.61           |
| 4.312            | 25.48             | -13.05           |
| 4.440            | 24.95             | -10.41           |
| 4.568            | 24.50             | -7.76            |
| 4.696            | 23.95             | -5.20            |
| 4.824            | 23.67             | -2.56            |
| 4.952            | 23.47             | 0.03             |
| 5.080            | 23.40             | 2.59             |
| 5.208            | 23.39             | 5.13             |
| 5.336            | 23.50             | 7.64             |
| 5.464            | 23.72             | 10.20            |

| FREQUENCY<br>GHz | RESISTANCE<br>(Ω) | REACTANCE<br>(Ω) |
|------------------|-------------------|------------------|
| 5.592            | 24.09             | 12.74            |
| 5.720            | 24.60             | 15.21            |
| 5.848            | 25.20             | 17.55            |
| 5.976            | 26.02             | 19.70            |
| 6.104            | 26.80             | 21.46            |
| 6.232            | 27.27             | 22.90            |
| 6.360            | 27.22             | 24.41            |
| 6.488            | 26.98             | 26.35            |
| 6.616            | 26.79             | 28.58            |
| 6.744            | 26.75             | 31.11            |
| 6.872            | 26.85             | 33.76            |
| 7.000            | 27.06             | 36.48            |

S11 Forward Reflection  
Impedance



0.6000GHz-7.000GHz

5535 TA03

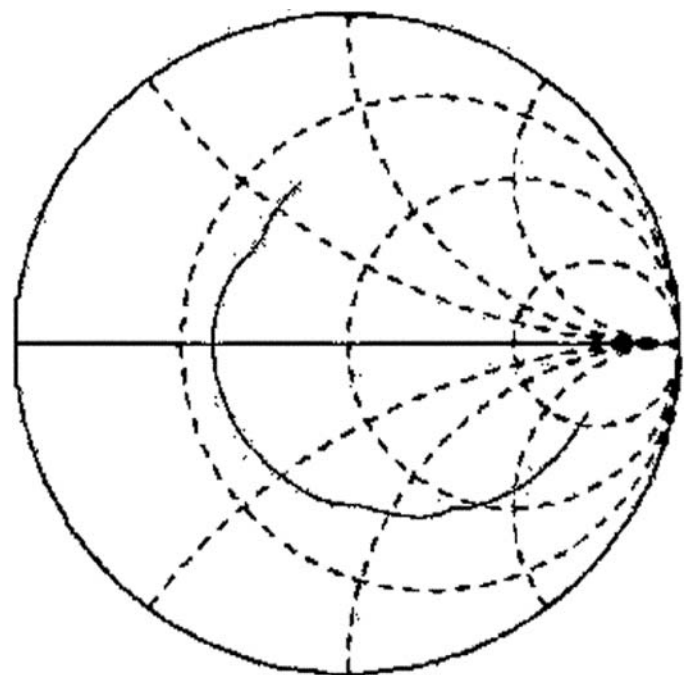
## TYPICAL PERFORMANCE CHARACTERISTICS

RF<sub>IN</sub> Input Impedance (Pin = 0dBm, V<sub>CC</sub> = 3.6V, T<sub>A</sub> = 25°C)

| FREQUENCY<br>(GHz) | RESISTANCE<br>(Ω) | REACTANCE<br>(Ω) |
|--------------------|-------------------|------------------|
| 0.600              | 176.00            | -174.00          |
| 0.728              | 148.00            | -165.00          |
| 0.856              | 125.00            | -153.00          |
| 0.984              | 108.00            | -143.00          |
| 1.112              | 94.80             | -133.00          |
| 1.240              | 83.20             | -123.00          |
| 1.368              | 74.60             | -115.00          |
| 1.496              | 67.50             | -107.00          |
| 1.624              | 61.40             | -99.00           |
| 1.752              | 56.80             | -92.90           |
| 1.880              | 52.70             | -86.10           |
| 2.008              | 49.30             | -80.00           |
| 2.136              | 47.10             | -74.40           |
| 2.264              | 45.30             | -70.00           |
| 2.392              | 42.40             | -66.70           |
| 2.520              | 39.60             | -62.30           |
| 2.648              | 37.70             | -58.60           |
| 2.776              | 36.30             | -55.00           |
| 2.904              | 35.10             | -51.00           |
| 3.032              | 34.00             | -47.70           |
| 3.160              | 33.20             | -44.60           |
| 3.288              | 32.10             | -41.80           |
| 3.416              | 30.70             | -39.50           |
| 3.544              | 29.10             | -36.70           |
| 3.672              | 27.70             | -33.70           |
| 3.800              | 26.60             | -30.60           |
| 3.928              | 25.70             | -27.70           |
| 4.056              | 25.00             | -25.10           |
| 4.184              | 24.10             | -22.10           |
| 4.312              | 23.50             | -19.50           |
| 4.440              | 22.90             | -17.10           |
| 4.568              | 22.40             | -14.00           |
| 4.696              | 22.00             | -11.40           |
| 4.824              | 21.70             | -8.83            |
| 4.952              | 21.30             | -5.99            |
| 5.080              | 21.20             | -3.45            |
| 5.208              | 21.20             | -0.77            |
| 5.336              | 21.20             | 1.70             |
| 5.464              | 21.40             | 4.46             |

| FREQUENCY<br>GHz | RESISTANCE<br>(Ω) | REACTANCE<br>(Ω) |
|------------------|-------------------|------------------|
| 5.592            | 21.80             | 7.14             |
| 5.720            | 22.10             | 9.55             |
| 5.848            | 22.70             | 12.00            |
| 5.976            | 23.60             | 14.40            |
| 6.104            | 24.20             | 15.90            |
| 6.232            | 24.70             | 17.80            |
| 6.360            | 24.70             | 19.30            |
| 6.488            | 24.30             | 21.40            |
| 6.616            | 24.10             | 23.80            |
| 6.744            | 24.00             | 26.30            |
| 6.872            | 24.00             | 28.80            |
| 7.000            | 24.10             | 31.40            |

S11 Forward Reflection  
Impedance



0.6000GHz-7.000GHz

5535 TA04

## PIN FUNCTIONS

**RF<sub>IN</sub> (Pin 1):** RF Input Voltage. Referenced to  $V_{CC}$ . A coupling capacitor must be used to connect to the RF signal source. The frequency range is 600MHz to 7GHz. This pin has an internal  $500\Omega$  termination, an internal Schottky diode detector and a peak detector capacitor.

**GND (Pin 2):** Ground.

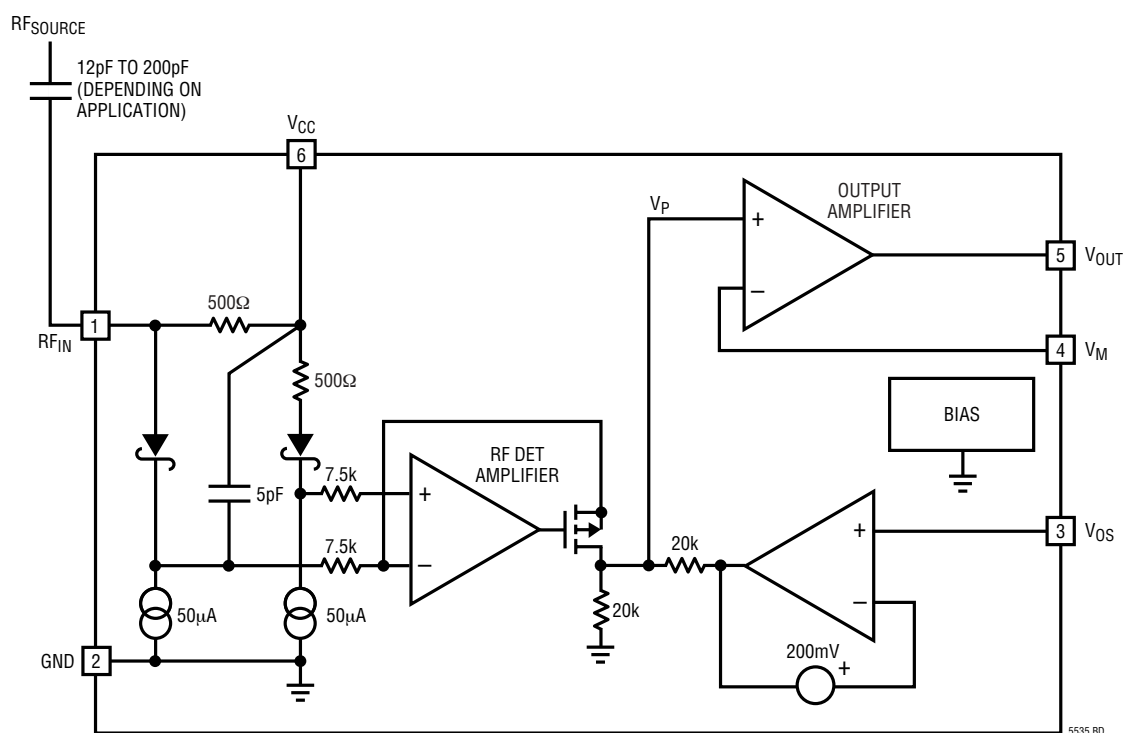
**V<sub>OS</sub> (Pin 3):** V<sub>OUT</sub> Offset Voltage Adjustment. From 0V to 200mV, V<sub>OUT</sub> does not change. Above 200mV, V<sub>OUT</sub> will track V<sub>OS</sub>.

**V<sub>M</sub> (Pin 4):** Negative Input to Output Amplifier.

**V<sub>OUT</sub> (Pin 5):** Detector Output.

**V<sub>CC</sub> (Pin 6):** Power Supply Voltage, 2.7V to 5.5V.  $V_{CC}$  should be bypassed appropriately with ceramic capacitors.

## BLOCK DIAGRAM



## APPLICATIONS INFORMATION

### Operation

The LTC5535 RF detector integrates several functions to provide RF power detection over frequencies ranging from 600MHz to 7GHz. These functions include an internal frequency compensated output amplifier, an RF Schottky diode peak detector and a level shift amplifier to convert the RF input signal to DC. The LTC5535 has both gain setting and voltage offset adjustment capabilities.

### Output Amplifier

The output amplifier is capable of supplying typically 20mA into a load. The negative terminal  $V_M$  is brought out to a pin for gain selection. External resistors connected between  $V_{OUT}$  and  $V_M$  ( $R_A$ ) and  $V_M$  to ground ( $R_B$ ) will set the gain of this amplifier.

$$\text{Gain} = 1 + R_A/R_B$$

The amplifier is not unity gain stable; a minimum gain of two is required. The output amplifier has a bandwidth of 20MHz with a gain of 2. For increased gain applications, the bandwidth is reduced according to the formula:

$$\text{Bandwidth} = 40\text{MHz}/(\text{Gain}) = 40\text{MHz} \cdot R_B/(R_A + R_B)$$

For stable operation the gain setting resistors should be low values and the board capacitance on  $V_M$  should be minimized.  $R_B$  is recommended to be no greater than 500Ω for all gain settings.

The  $V_{OS}$  input controls the DC input voltage to the output amplifier.  $V_{OS}$  must be connected to ground if the DC output voltage is not to be changed. The output amplifier is initially trimmed to 200mV (Gain = 2) with  $V_{OS}$  connected to ground.

The  $V_{OS}$  pin is used to change the initial  $V_{OUT}$  starting voltage. This function, in combination with gain adjustment enables the LTC5535 output to span the input range of a variety of analog-to-digital converters.  $V_{OUT}$  will not change until  $V_{OS}$  exceeds 200mV. The starting voltage at  $V_{OUT}$  for  $V_{OS} > 200\text{mV}$  is:

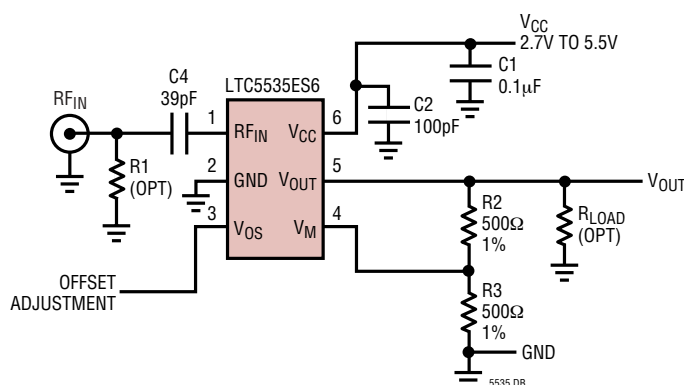
$$V_{OUT} = 0.5 \cdot V_{OS} \cdot \text{Gain}$$

where gain is the output amplifier gain. For a gain of 2,  $V_{OUT}$  will exactly track  $V_{OS}$  above 200mV.

### RF Detector

The internal RF Schottky diode peak detector and level shift amplifier converts the RF input signal to a low frequency signal. The detector demonstrates excellent efficiency and linearity over a wide range of input power. The Schottky diode is biased at about 50μA and drives a 5pF internal peak detector capacitor.

Demo Board Schematic



APPLICATIONS INFORMATION

Applications

The LTC5535 can be used as a self-standing signal strength measuring receiver for a wide range of input signals from -32dBm to 10dBm for frequencies from 600MHz to 7GHz.

The LTC5535 offers increased baseband bandwidth compared to other Schottky diode detectors. Table 1 shows that the baseband (demodulation) bandwidth is typically 12MHz at an RF input signal level of -10dBm. The baseband bandwidth is largely independent of the RF input signal frequency over the range of 600MHz to 7GHz.

Table 1

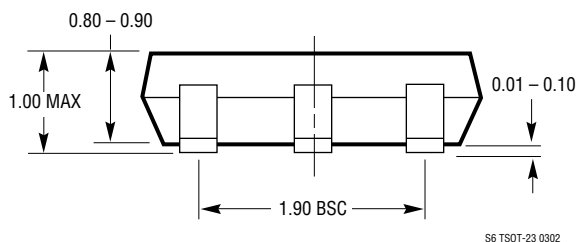
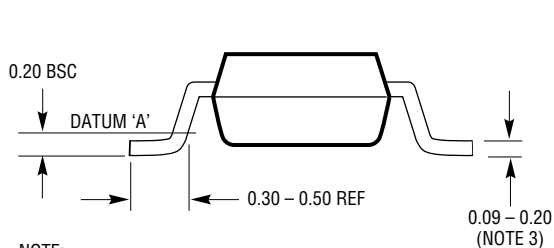
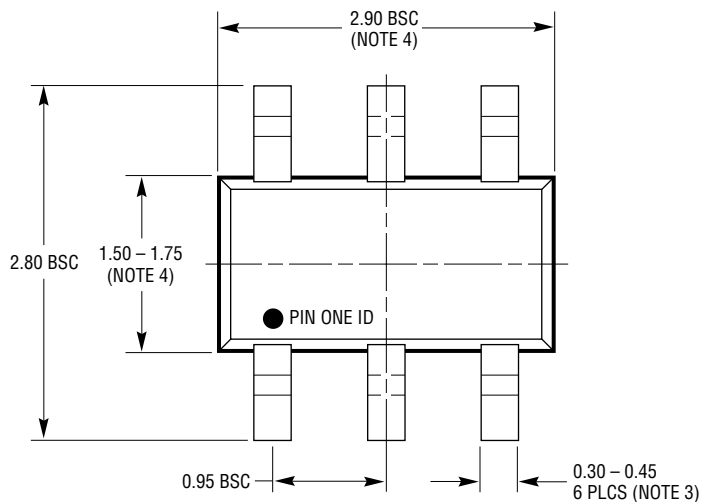
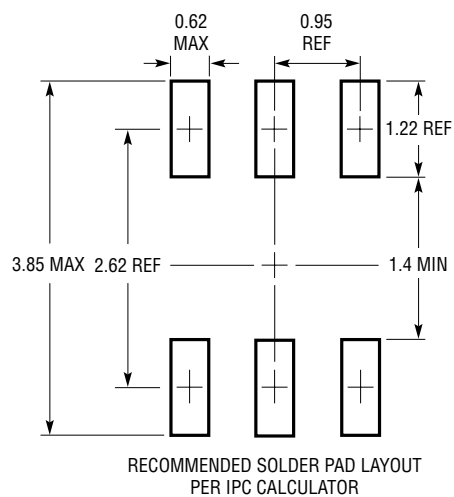
| INPUT LEVEL<br>(dBm) | OUTPUT BW<br>-3dB (MHz) | FREQUENCY<br>(GHz) | GAIN |
|----------------------|-------------------------|--------------------|------|
| -20                  | 12.5                    | 3                  | 2    |
| -10                  | 12                      | 3                  | 2    |
| -5                   | 11                      | 3                  | 2    |
| 0                    | 9.5                     | 3                  | 2    |

Operation at higher RF input frequencies is achievable. Consult factory for more information.

The LTC5535 can be used as a demodulator for AM and ASK modulated signals. Depending on specific application needs, the RSSI output can be split between two branches, providing AC-coupled data (or audio) output and a DC-coupled RSSI output for signal strength measurements and AGC.

## PACKAGE DESCRIPTION

**S6 Package**  
**6-Lead Plastic TSOT-23**  
 (Reference LTC DWG # 05-08-1636)



- NOTE:
1. DIMENSIONS ARE IN MILLIMETERS
  2. DRAWING NOT TO SCALE
  3. DIMENSIONS ARE INCLUSIVE OF PLATING
  4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
  5. MOLD FLASH SHALL NOT EXCEED 0.254mm
  6. JEDEC PACKAGE REFERENCE IS MO-193

S6 TSOT-23 0302

## RELATED PARTS

| PART NUMBER                 | DESCRIPTION                                                            | COMMENTS                                                                                                             |
|-----------------------------|------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------|
| <b>Infrastructure</b>       |                                                                        |                                                                                                                      |
| LT <sup>®</sup> 5511        | High Linearity Upconverting Mixer                                      | RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer                                                                  |
| LT5512                      | DC-3GHz High Signal Level Downconverting Mixer                         | DC to 3GHz, 21dBm IIP3, Integrated LO Buffer                                                                         |
| LT5514                      | Ultralow Distortion IF Amplifier/ADC Driver                            | Digitally Controlled Gain, 47dBm OIP3 at 100MHz                                                                      |
| LT5515                      | 1.5GHz to 2.5GHz Direct Conversion Quadrature Demodulator              | 20dBm IIP3, Integrated LO Quadrature Generator                                                                       |
| LT5516                      | 0.8GHz to 1.5GHz Direct Conversion Quadrature Demodulator              | 21.5dBm IIP3, Integrated LO Quadrature Generator                                                                     |
| LT5517                      | 40MHz to 900MHz Direct Conversion Quadrature Demodulator               | 21dBm IIP3, Integrated LO Quadrature Generator                                                                       |
| LT5519                      | 0.7GHz to 1.4GHz High Linearity Upconverting Mixer                     | 17.1dBm IIP3, 50 $\Omega$ Single Ended RF and LO Ports                                                               |
| LT5520                      | 1.3GHz to 2.3GHz High Linearity Upconverting Mixer                     | 15.9dBm IIP3, 50 $\Omega$ Single Ended RF and LO Ports                                                               |
| LT5521                      | Very High Linearity Active Mixer                                       | 24dBm IIP3, -42dBm LO Leakage at 1950MHz                                                                             |
| LT5522                      | 600MHz to 2.7GHz High Linearity Downconverting Mixer                   | 4.5V to 5.25V Supply, 25dBm IIP3 at 900MHz, NF = 12.5dB, 50 $\Omega$ Single-Ended RF and LO Ports                    |
| <b>RF Power Detectors</b>   |                                                                        |                                                                                                                      |
| LT5504                      | 800MHz to 2.7GHz RF Measuring Receiver                                 | 80dB Dynamic Range, Temperature Compensated, 2.7V to 5.25V Supply                                                    |
| LTC5505                     | 300MHz to 3GHz RF Power Detectors                                      | LTC5505-1: -28dBm to 18dBm Range,<br>LTC5505-2: -32dBm to 12dBm Range,<br>Temperature Compensated, 2.7V to 6V Supply |
| LTC5507                     | 100kHz to 1000MHz RF Power Detector                                    | -34dBm to 14dBm Range, Temperature Compensated, 2.7V to 6V Supply                                                    |
| LTC5508                     | 300MHz to 7GHz RF Power Detector                                       | -32dBm to 12dBm Range, Temperature Compensated, SC70 Package                                                         |
| LTC5509                     | 300MHz to 3GHz RF Power Detector                                       | 36dB Dynamic Range, Temperature Compensated, SC70 Package                                                            |
| LTC5532                     | 300MHz to 7GHz Precision RF Power Detector                             | Precision $V_{OUT}$ Offset Control, Adjustable Gain and Offset                                                       |
| LT5534                      | 50MHz to 3GHz RF Power Detector                                        | 60dB Dynamic Range, Temperature Compensated                                                                          |
| <b>RF Building Blocks</b>   |                                                                        |                                                                                                                      |
| LT5500                      | 1.8GHz to 2.7GHz Receiver Front End                                    | 1.8V to 5.25V Supply, Dual-Gain LNA, Mixer, LO Buffer                                                                |
| LT5502                      | 400MHz Quadrature IF Demodulator with RSSI                             | 1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range                                        |
| LT5503                      | 1.2GHz to 2.7GHz Direct IQ Modulator and Upconverting Mixer            | 1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth                                        |
| LT5506                      | 500MHz Quadrature IF Demodulator with VGA                              | 1.8V to 5.25V Supply, 40MHz to 500MHz IF, -4dB to 57dB Linear Power Gain, 8.8MHz Baseband Bandwidth                  |
| LT5546                      | 500MHz Quadrature IF Demodulator with VGA and 17MHz Baseband Bandwidth | 17MHz Baseband Bandwidth, 40MHz to 500MHz IF, 1.8V to 5.25V Supply, -7dB to 56dB Linear Power Gain                   |
| <b>RF Power Controllers</b> |                                                                        |                                                                                                                      |
| LTC1757A                    | RF Power Controller                                                    | Multiband GSM/DCS/GPRS Mobile Phones                                                                                 |
| LTC1758                     | RF Power Controller                                                    | Multiband GSM/DCS/GPRS Mobile Phones                                                                                 |
| LTC1957                     | RF Power Controller                                                    | Multiband GSM/DCS/GPRS Mobile Phones                                                                                 |
| LTC4400                     | SOT-23 RF PA Controller                                                | Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW                                                    |
| LTC4401                     | SOT-23 RF PA Controller                                                | Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW                                                    |
| LTC4402                     | RF Power Controller for EDGE/TDMA                                      | Multiband GSM/GPRS/EDGE Mobile Phones, 450kHz Loop BW                                                                |
| LTC4403                     | RF Power Controller for EDGE/TDMA                                      | Multiband GSM/GPRS/EDGE Mobile Phones, 250kHz Loop BW                                                                |



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

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- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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